Appl. No. 09/545,785 Amendment and/ r Respons Reply to Offic acti n of 20 May 2003 # 24 /E
Page 1 of 13
W/DY 4WING 9/3/03
ATTACK: 4/3/03

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Appl. No.

09/545.785

Applicants

: Tirdad SOWLATI et al.

Filed

7 April 2000 -

TC/A.U.

: 2811

Examiner

Ori NADAV

Atty. Docket

US000099A

Title:

INTERDIGITATED MULTILAYER CAPACITOR STRUCTURE FOR DEEP SUB-MICRON CMOS

AMENDMENT and/or RESPONSE under 37 C.F.R. § 1.112

Mail Stop Non-Fee Amendment Commissioner for Patents P.O. Box 1450 Alexandria, VA 22313-1450

Sir:

In response to the non-final Office action of 20 May 2003, please amend the above referenced application as follows and reconsider the application in light of the following remarks.

This paper includes (each beginning on a separate sheet):

- 1. Listing of the claims;
- 2. Amendments to the drawing figures;
- 3. Remarks/Discussion of issues;
- 4. Attached replacement drawing sheet;
- 5. Annotated drawing sheet showing changes.

CERTIFICATE OF MAILING OR TRANSMISSION

I certify that this correspondence is being:

[] deposited with the U.S. Postal Service with sufficient postage as first-class mail in an envelope addressed to the Commissioner for Patents, P.O. Box 1450, Alexandria, VA 22313-1450.

[] transmitted by facsimile to the U.S. Patent and Trademark Office at 703On: _______

By: ______